

VS-30ETH06FP-F3, VS-30ETH06FP-N3

Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt[®]



TO-220 FULL-PAK

PRODUCT SUMMARY				
Package	TO-220FP			
I _{F(AV)}	30 A			
V _R	600 V			
V _F at I _F	2.6 V			
t _{rr} (typ.)	23 ns			
T _J max.	175 °C			
Diode variation	Single die			

FEATURES

- Reduced Q_{rr} and soft recovery
- 175 °C T_{.1} maximum
- For PFC CRM/CCM operation
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 pending
- Compliant to RoHS Directive 2002/95/EC
- FREE Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V _{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 37 °C	30	٨	
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	220	A	
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage V _F	I _F = 30 A	-	2.00	2.60	V	
	$I_F = 30 \text{ A}, T_J = 150 \text{ °C}$	-	1.34	1.75		
Reverse leakage current	1	V _R = V _R rated	-	0.3	50	
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	60	500	μA
Junction capacitance	CT	V _R = 600 V	-	33	-	pF
Series inductance	Ls	Measured lead to lead 5 mm from package body	-	8	-	nH

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RoHS

COMPLIANT

HALOGEN



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	28	35	
Reverse recovery time t _{rr}	+	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{V}_R = 30 \text{ V}$		-	23	30	ns
	T _J = 25 °C		-	31	-		
		T _J = 125 °C		-	77	-	
Peak recovery current I _{RRM}	T _J = 25 °C	$I_F = 30 A$	-	3.5	-	٨	
	IRRM	T _J = 125 °C	dI _F /dt = 200 A/µs V _R = 200 V	-	7.7	-	A
Reverse recovery charge Q _{rr}	Q _{rr}	T _J = 25 °C	11	-	65	-	nC
		T _J = 125 °C		-	345	-	пс

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	-	2.85	
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	
Weight			-	2	-	g
weight			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-220 FULL-PAK		30ETH	H06FP	

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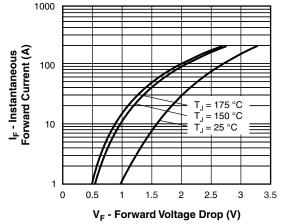
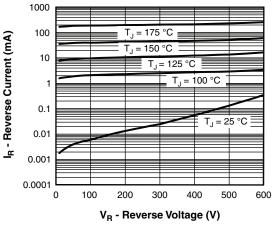
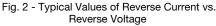


Fig. 1 - Typical Forward Voltage Drop Characteristics





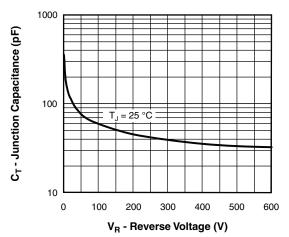


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

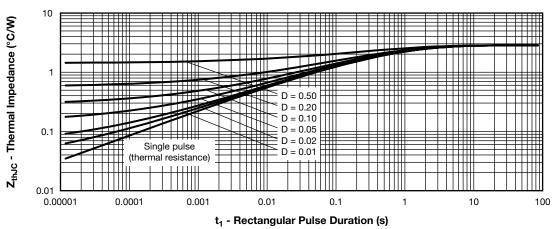


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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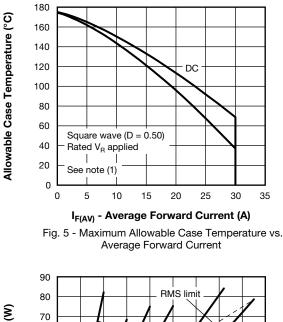
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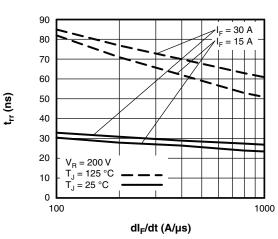
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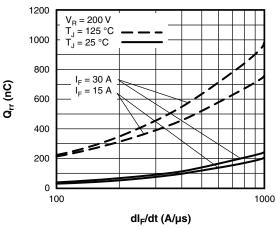
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Average Power Loss (W)

60

50

40

30

20

10

0

0 5 10

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \, \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \, \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics

15 20 25 30 D = 0.01

D = 0.02

D = 0.05

D = 0.10D = 0.20

D = 0.50

35 40 45

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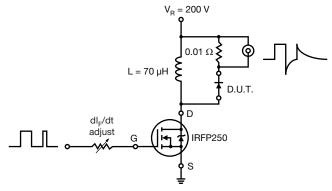
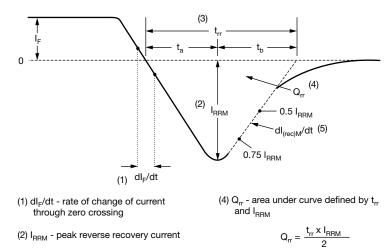


Fig. 9 - Reverse Recovery Parameter Test Circuit



(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

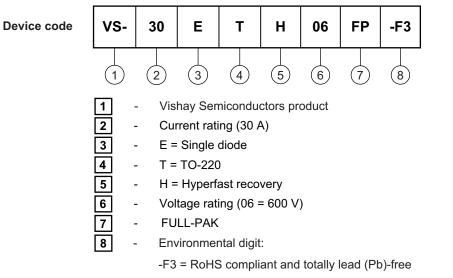
Fig. 10 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE



-N3 = Halogen-free, RoHS compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-30ETH06FP-F3	50	1000	Antistatic plastic tube		
VS-30ETH06FP-N3	50	1000	Antistatic plastic tube		

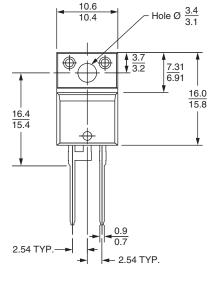
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95005				
Part marking information	www.vishay.com/doc?95440			



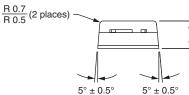
Outline Dimensions

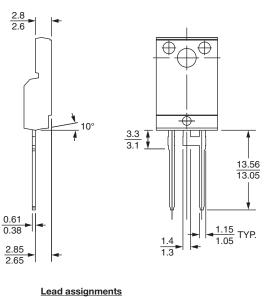
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DIMENSIONS in millimeters



 $\frac{4.8}{4.6}$





<u>Lead assignments</u> <u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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